SEMTECH

SLVE2.8 and SLVG2.8

PROTECTION PRODUCTS

Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20µs)	P _{pk}	300	Watts
Peak Pulse Current (tp = 8/20µs)	۱ _{pp}	24	А
Lead Soldering Temperature	TL	260 (10 seconds)	°C
Operating Temperature	T,	-55 to +125	٥C
Storage Temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics

SLVE2.8						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V _{RWM}				2.8	V
Punch-Through Voltage	V _{PT}	Ι _{ΡΤ} = 2μΑ	3.0			V
Snap-Back Voltage	V _{SB}	I _{sb} = 50mA	2.8			V
Reverse Leakage Current	I _R	$V_{_{RWM}} = 2.8V, T = 25^{\circ}C$			1	μA
Clamping Voltage	V _c	$I_{pp} = 1A, t_p = 8/20\mu s$			4.1	V
Clamping Voltage	V _c	$I_{pp} = 5A, t_p = 8/20\mu s$			5.3	V
Clamping Voltage	V _c	I _{PP} = 24A, tp = 8/20µs			15	V
Junction Capacitance	C _j	Line-to-Line V _R = OV, f = 1MHz			100	pF

SLVG2.8							
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units	
Reverse Stand-Off Voltage	V _{RWM}				2.8	V	
Punch-Through Voltage	V _{PT}	Ι _{ΡΤ} = 2μΑ	3.0			V	
Snap-Back Voltage	V _{SB}	I _{sb} = 50mA	2.8			V	
Reverse Leakage Current	I _R	V _{RWM} = 2.8V, T=25°C			1	μA	
Clamping Voltage	V _c	$I_{pp} = 1A, t_p = 8/20\mu s$			4.1	V	
Clamping Voltage	V _c	$I_{pp} = 5A, t_p = 8/20\mu s$			5.3	V	
Clamping Voltage	V _c	$I_{pp} = 24A, t_p = 8/20\mu s$			15	V	
Junction Capacitance	C _j	Line-to-Line $V_{R} = OV, f = 1MHz$			50	pF	

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Typical Characteristics

Non-Repetitive Peak Pulse Power vs. Pulse Time



Pulse Waveform



Power Derating Curve % of Rated Power or I_{PP} Ambient Temperature - T_A (°C)

Clamping Voltage vs. Peak Pulse Current



SLVE2.8 and SLVG2.8



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Applications Information

Device Connection

Electronic equipment is susceptible to transient disturbances from a variety of sources including: ESD to an open connector or interface, direct or nearby lightning strikes to cables and wires, and charged cables "hot plugged" into I/O ports. The SLV series is designed to protect sensitive components from damage and latchup which may result from such transient events. The SLVG2.8 is designed to protect one unidirectional line while the SLVE2.8 is designed to protect one bidirectional line (or two differential lines). The options for connecting the devices are as follows:

- SLVE2.8: Common mode protection of one bidirectional data line is achieved by connecting the data line input/output at pins 2 and 3. Pins 1 and 4 are connected to ground. For differential protection, pins 1 and 4 can be connected to a second I/O line. For best results, the ground connection should be made directly to a ground plane on the board. The path length should be kept as short as possible to minimize parasitic inductance.
- SLVG2.8: Common mode protection of one unidirectional line is achieved by connecting the line to be protected at pins 2 and 3. Pins 1 and 4 are connected to ground. For best results, the ground connection should be made directly to a ground plane on the board. The path length should be kept as short as possible to minimize parasitic inductance.

Circuit Board Layout Recommendations for Suppression of ESD.

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

Circuit Diagrams

Common Mode Protection (SLVE2.8 and SLVG2.8)



Differential Mode Protection (SLVE2.8 only)



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SLVE2.8 and SLVG2.8



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Applications Information (continued)

EPD TVS[™] Characteristics

The SLV series is constructed using Semtech's proprietary EPD technology. The structure of the EPD TVS is vastly different from the traditional pn-junction devices. At voltages below 5V, high leakage current and junction capacitance render conventional avalanche technology impractical for most applications. However, by utilizing the EPD technology, the SLVE2.8 and SLVG2.8 can effectively operate at 2.8V while maintaining excellent electrical characteristics.

The EPD TVS employs a complex nppn structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. The EPD mechanism is achieved by engineering the center region of the device such that the reverse biased junction does not avalanche, but will "punch-through" to a conducting state. This structure results in a device with superior dc electrical parameters at low voltages while maintaining the capability to absorb high transient currents.

The IV characteristic curve of the EPD device is shown in Figure 1. The device represents a high impedance to the circuit up to the working voltage (V_{RWM}). During a transient event, the device will begin to conduct as it is biased in the reverse direction. When the punchthrough voltage (V_{PT}) is exceeded, the device enters a low impedance state, diverting the transient current away from the protected circuit. When the device is conducting current, it will exhibit a slight "snap-back" or negative resistance characteristic due to its structure. This must be considered when connecting the device to a power supply rail. To return to a non-conducting state, the current through the device must fall below the snap-back current (approximately < 50mA).







PROTECTION PRODUCTS

Outline Drawing - SOT-143



	DIMENSIONS					
	INCHES		M	NOTE		
	MIN	MAX	MIN	MAX	NOIL	
А	.110	.120	2.80	3.04	—	
В	.047	.055	1.20	1.40	—	
С	.031	.047	.800	1.20	—	
D	.014	.018	.370	.460	—	
E	.030	.035	.760	.890	—	
G	.076	BSC	1.92	BSC	—	
H	.068	BSC	1.72	BSC	—	
J	.003	.007	.085	.180	—	
K	.001	.004	.013	0.10	—	
L	—	.022	_	.55	REF	
S	.082	.104	2.10	2.64	_	

Notes:

(1) Controlling dimension: Millimeters.

(2) Dimension A and B do not include mold protrusions.

Mold protrusions are .006" max.

Land Pattern - SOT-143





PROTECTION PRODUCTS

Marking Codes

Part Number	Marking Code
SLVE2.8	E2.8
SLVG2.8	G2.8

Ordering Information

Part Number	Working Voltage	Qty per Reel	Reel Size
SLVE2.8.TC	2.8V	3,000	7 Inch
SLVG2.8.TC	2.8V	3,000	7 Inch

Note: Consult factory for availability of 13" reels

Contact Information

Semtech Corporation Protection Products Division 200 Flynn Road, Camarillo, CA 93012 Phone: (805)498-2111 FAX (805)498-3804